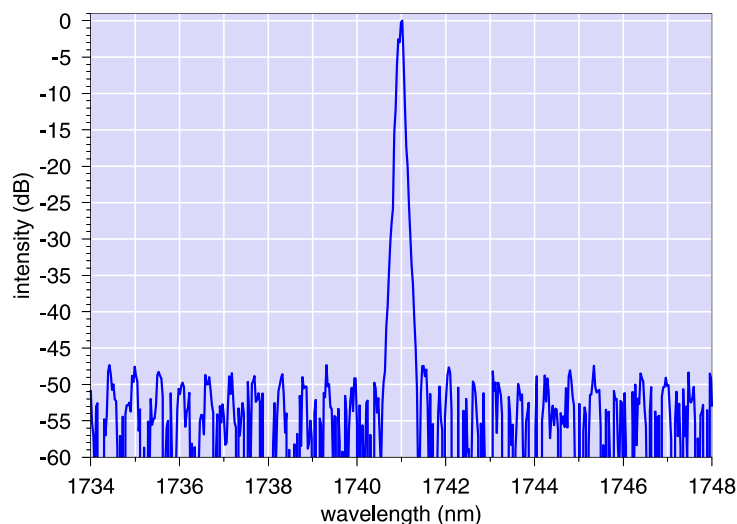


DFB laser diodes for 1700nm applications

Device protected by US patent no. 6,671,306

description

nanoplus 1700nm DFB laser diodes (in the following a 1742nm device is exemplary presented) show unique device performance to meet the requirements of our customers. Their high side mode suppression ratio (SMSR) and high spectral purity make them perfectly suited for applications like e.g. HCI spectroscopy. Mode-hop free DFB emission with a high side mode suppression ratio (SMSR) around 35dB is guaranteed for the device in the entire specified temperature and current range of operation. In addition to QW active material, QD material with unique performance is also available in this wavelength range upon request.



specifications

Parameter	Symbol	Unit	min	typical	max
Wavelength		nm	1741	1742	1743
Side mode suppression		db		35	
Optical output power	P_{opt}	mW		3	
Forward current	I_f	mA	70	80	100
Threshold current	I_{th}	mA	25	30	45
Beam divergence parallel		deg.	25	30	35
Beam divergence perpendicular		deg.	45	50	60
Slope efficiency	e	mW/mA	0.1	0.16	0.2
Current tuning rate	C_I	nm/mA	0.008	0.01	0.12
Temperature tuning rate	C_T	nm/K	0.08	0.1	0.12

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■ absolute maximum ratings

Parameter	Symbol	Unit	Rating
LD forward current	I_f	mA	120
Operating temperature	T_{op}	deg C	-20-50
Storage temperature	T_{store}	deg C	-20-85

■ applications

- HCl sensing

■ packaging

nanoplus offers a wide variety of different packaging options for their FP and DFB laser diodes in the entire wavelength range, including all standardized TO headers (e.g. TO 5.6 mm, TO 9 mm, TO 8) with or without Peltier cooler. Please refer to our *packaging datasheet* for more information.

Other customized packages (e.g. mounting on customer specific submounts) are available upon request. Please do not hesitate to contact us for further details.

